## NSN 5961-01-224-5433

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-224-5433 **Inclosure Material:** Glass **Overall Length:** 0.165 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.070 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Precious Material And Location:** Leads plated gold **Precious Material:** Gold **Test Data Document:** 80063-a3012732 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**